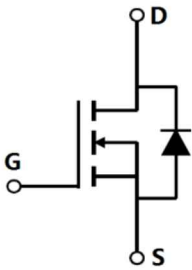


■ General Description

OSG07N65x use advanced GreenMOS™ technology to provide low $R_{DS(ON)}$, low gate charge, fast switching and excellent avalanche characteristics. This device is suitable for active power factor correction and switching mode power supply applications.

◆ $V_{DS, \min @ T_{jmax}}$	700 V
◆ $I_{D, \text{pulse}}$	13.5 A
◆ $R_{DS(ON), \text{max @ } V_{GS}=10 \text{ V}}$	1.0 Ω
◆ Q_g	7.0 nC

■ Schematic and Package Information

Schematic Diagram	Pin Assignment Top View
	 TO251 OSG07N65A  TO252 OSG07N65D  TO220F OSG07N65F  TO220 OSG07N65P

■ Absolute Maximum Ratings at $T_j=25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Value	Unit
Drain source voltage	V_{DS}	650	V
Gate source voltage	V_{GS}	± 30	V
Continuous drain current ¹⁾	I_D	4.5	A
Continuous drain current ¹⁾ $T_j=100^\circ\text{C}$		2.8	
Pulsed drain current ²⁾	$I_{D, \text{pulse}}$	13.5	A
Power dissipation ³⁾ for TO251, TO252, TO220	P_D	28.4	W
Power dissipation ³⁾ for TO220F		24	
Single pulsed avalanche energy ⁵⁾	E_{AS}	100	mJ
MOSFET dv/dt ruggedness, $V_{DS}=0\ldots 480 \text{ V}$	dv/dt	50	V/ns
Reverse diode dv/dt, $V_{DS}=0\ldots 480 \text{ V}$, $I_{SD} \leq I_D$	dv/dt	15	V/ns
Operation and storage temperature	T_{stg}, T_j	-55 to 150	$^\circ\text{C}$

■ Thermal Characteristics

Parameter	Symbol	Value		Unit
		TO251/TO252/TO220	TO220F	
Thermal resistance, junction-case	$R_{\theta JC}$	4.4	5.2	°C/W
Thermal resistance, junction-ambient ⁴⁾	$R_{\theta JA}$	62	62.5	°C/W

■ Electrical Characteristics at $T_j=25\text{ }^{\circ}\text{C}$ unless otherwise specified

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition
Drain-source breakdown voltage	BV_{DSS}	650			V	$V_{GS}=0\text{ V}$, $I_D=250\text{ }\mu\text{A}$
		700	770			$V_{GS}=0\text{ V}$, $I_D=250\text{ }\mu\text{A}$ $T_j=150\text{ }^{\circ}\text{C}$
Gate threshold voltage	$V_{GS(th)}$	2.0		4.0	V	$V_{DS}=V_{GS}$, $I_D=250\text{ }\mu\text{A}$
Drain-source on-state resistance	$R_{DS(on)}$		0.9	1.0	Ω	$V_{GS}=10\text{ V}$, $I_D=2\text{ A}$
			2.16			$V_{GS}=10\text{ V}$, $I_D=2\text{ A}$, $T_j=150\text{ }^{\circ}\text{C}$
Gate-source leakage current	I_{GSS}			100	nA	$V_{GS}=30\text{ V}$
				-100		$V_{GS}=-30\text{ V}$
Drain-source leakage current	I_{DSS}			1	μA	$V_{DS}=650\text{ V}$, $V_{GS}=0\text{ V}$

■ Dynamic Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition
Input capacitance	C_{iss}		251.2		pF	$V_{GS}=0\text{ V}$, $V_{DS}=50\text{ V}$, $f=1\text{ MHz}$
Output capacitance	C_{oss}		29.7		pF	
Reverse transfer capacitance	C_{rss}		1.3		pF	
Turn-on delay time	$t_{d(on)}$		31.3		ns	$V_{GS}=10\text{ V}$, $V_{DS}=400\text{ V}$, $R_G=25\text{ }\Omega$, $I_D=3\text{ A}$
Rise time	t_r		17.4		ns	
Turn-off delay time	$t_{d(off)}$		67.7		ns	
Fall time	t_f		27.5		ns	

■ Gate Charge Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition
Total gate charge	Q_g		7.0		nC	$I_D=3\text{ A}$, $V_{DS}=400\text{ V}$, $V_{GS}=10\text{ V}$
Gate-source charge	Q_{gs}		1.9		nC	
Gate-drain charge	Q_{gd}		3.2		nC	
Gate plateau voltage	V_{plateau}		5.6		V	

■ Body Diode Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition
Diode forward current	I_S			4.5	A	$V_{GS}<V_{th}$
Pulsed source current	I_{SP}			13.5		
Diode forward voltage	V_{SD}			1.3	V	$I_S=4.5\text{ A}$, $V_{GS}=0\text{ V}$
Reverse recovery time	t_{rr}		204.8		ns	$V_R=400\text{ V}$, $I_S=3\text{ A}$, $di/dt=100\text{ A}/\mu\text{s}$
Reverse recovery charge	Q_{rr}		1.1		μC	
Peak reverse recovery current	I_{rrm}		12.1		A	

■ Note

- 1) Calculated continuous current based on maximum allowable junction temperature.
- 2) Repetitive rating; pulse width limited by max. junction temperature.
- 3) P_d is based on max. junction temperature, using junction-case thermal resistance.
- 4) The value of $R_{\theta JA}$ is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with $T_a=25\text{ }^{\circ}\text{C}$.
- 5) $V_{DD}=100\text{ V}$, $R_G=25\text{ }\Omega$, $L=20\text{ mH}$, starting $T_j=25\text{ }^{\circ}\text{C}$.

■ Electrical Characteristics Diagrams

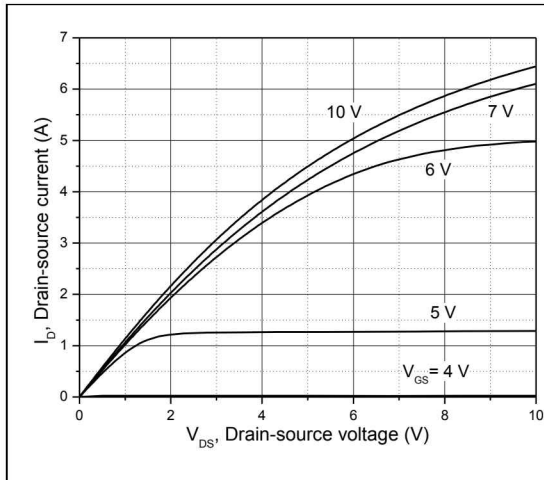


Figure 1, Typ. output characteristics

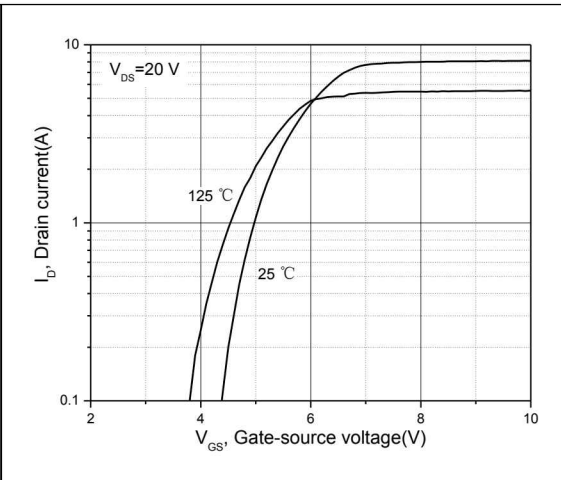


Figure 2, Typ. transfer characteristics

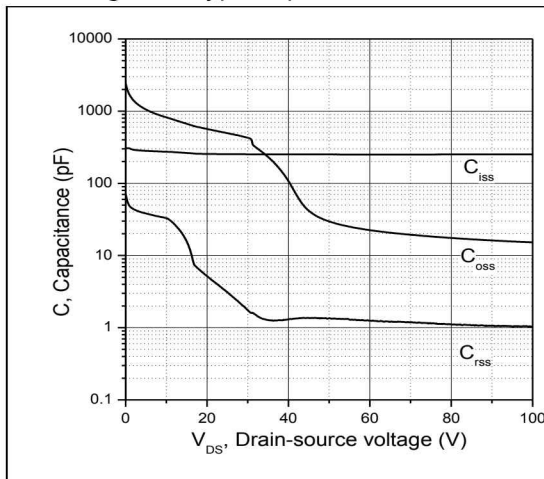


Figure 3, Typ. capacitances

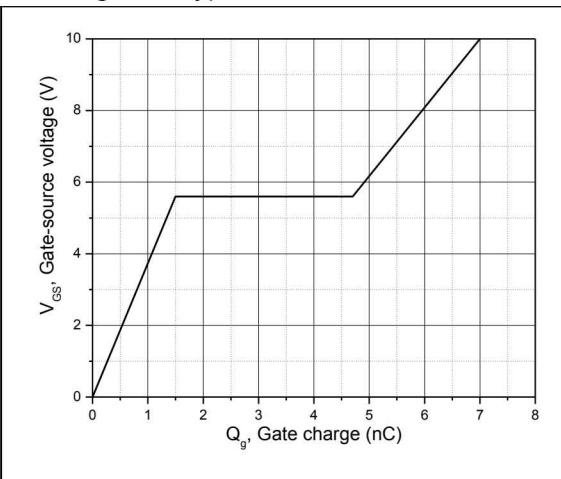


Figure 4, Typ. gate charge

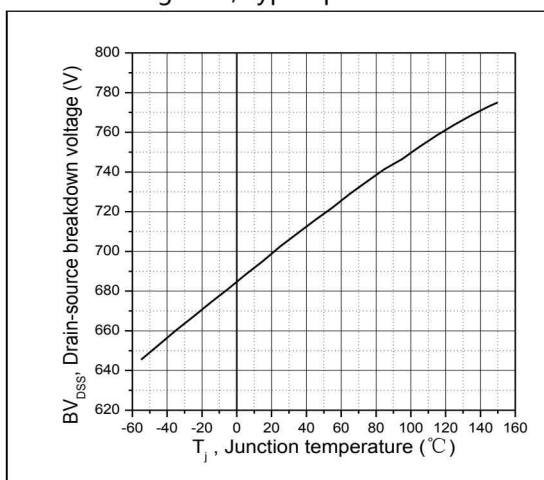


Figure 5, Drain-source breakdown voltage

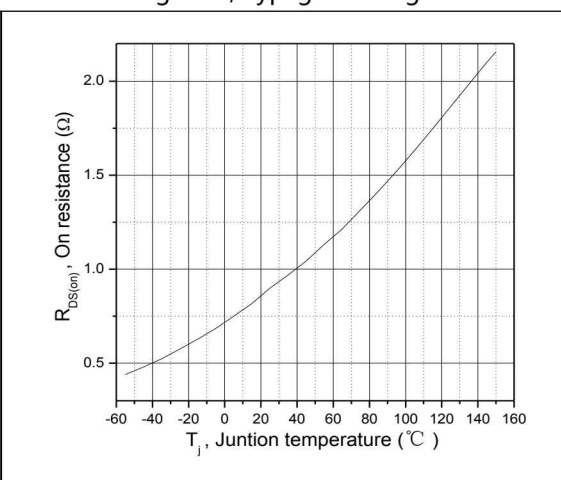


Figure 6, Drain-source on-state resistance

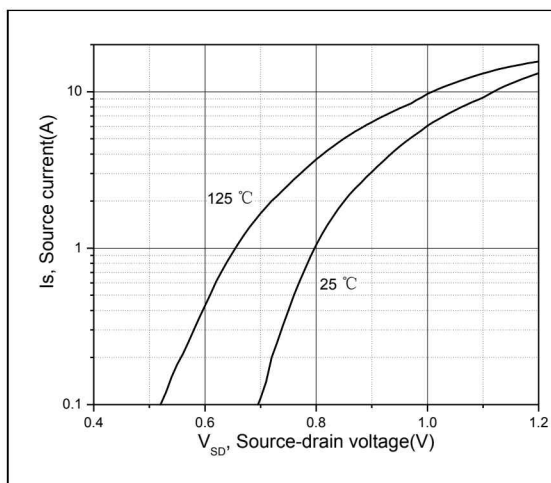


Figure 7, Forward characteristic of body diode

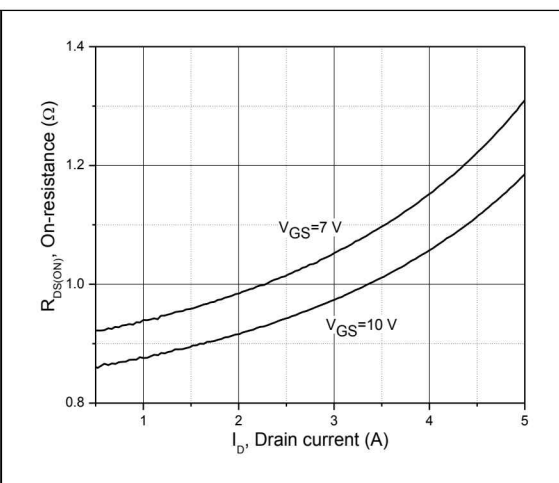


Figure 8, Drain-source on-state resistance

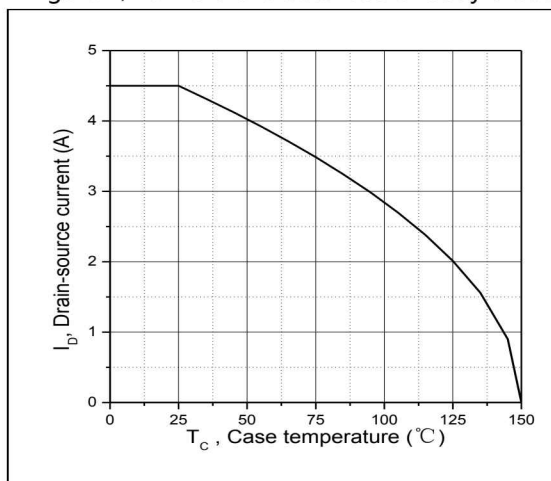


Figure 9, Drain current

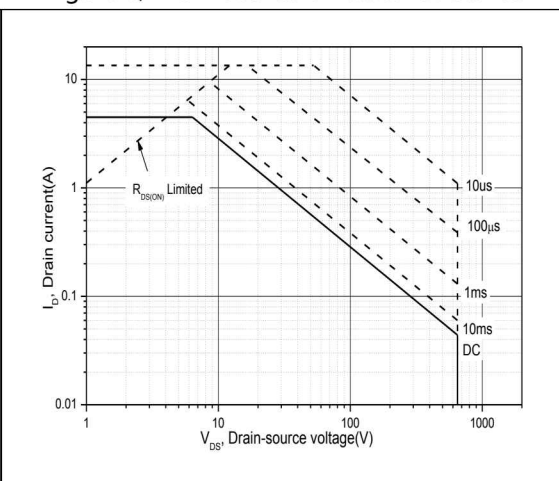


Figure 10, Safe operation area for
TO251/TO252/TO220 $T_C=25\text{ }^{\circ}\text{C}$

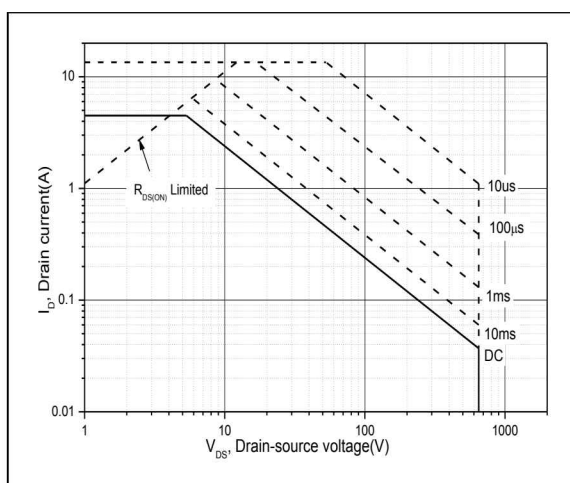


Figure 11, Safe operation area for TO220F
 $T_C=25\text{ }^{\circ}\text{C}$

■ Test circuits and waveforms

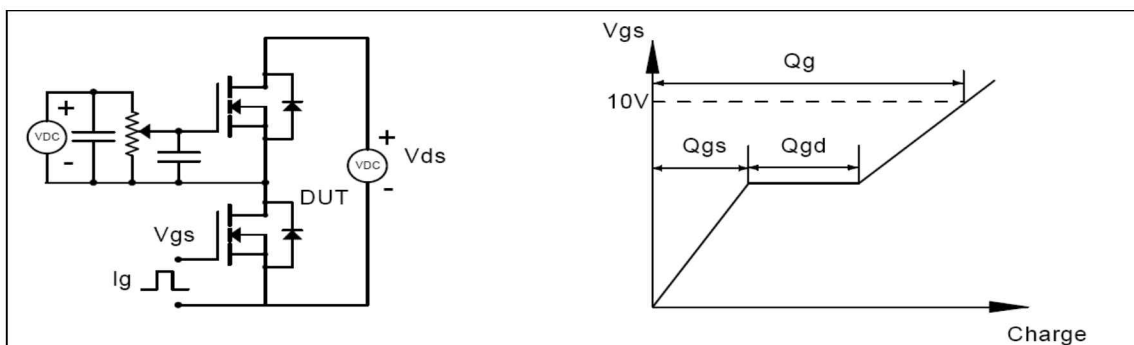


Figure 1, Gate charge test circuit & waveform

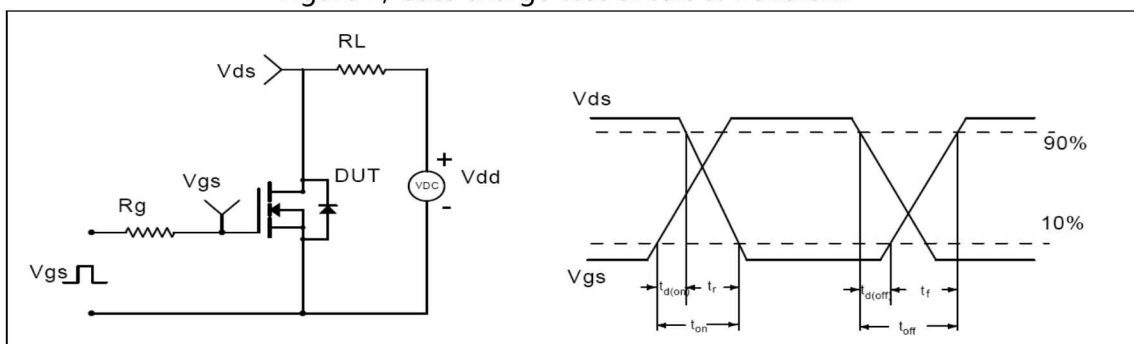


Figure 2, Switching time test circuit & waveforms

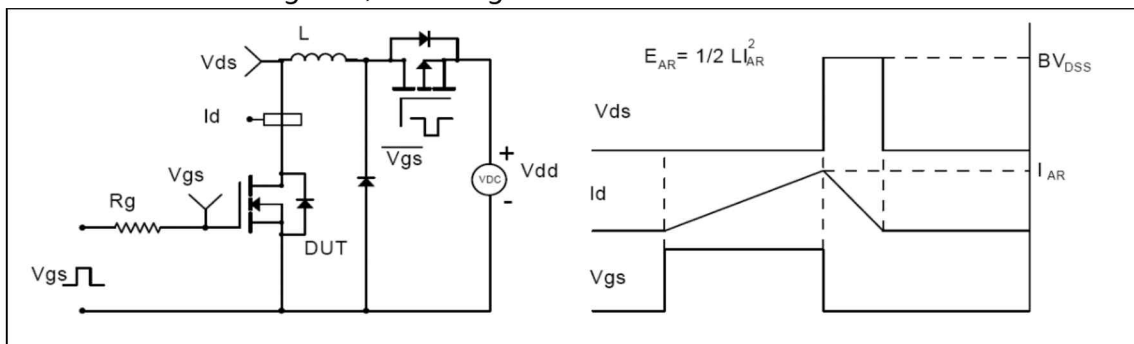


Figure 3, Unclamped inductive switching (UIS) test circuit & waveforms

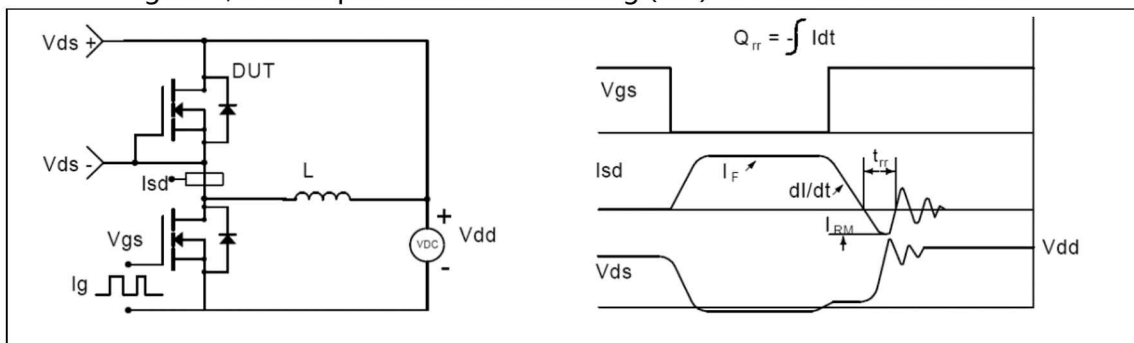
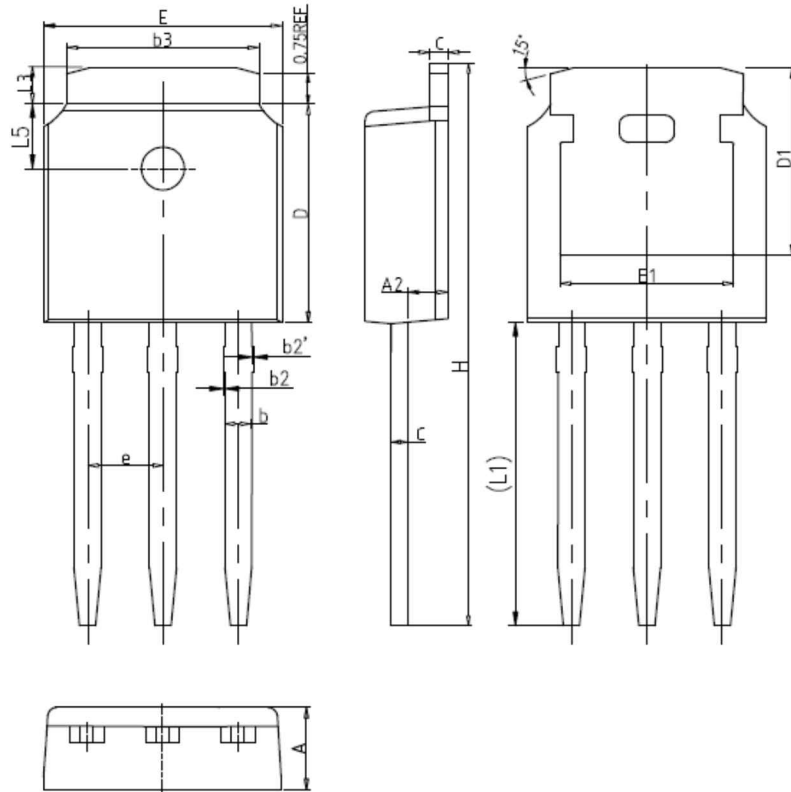


Figure 4, Diode reverse recovery test circuit & waveforms

■ Package Information

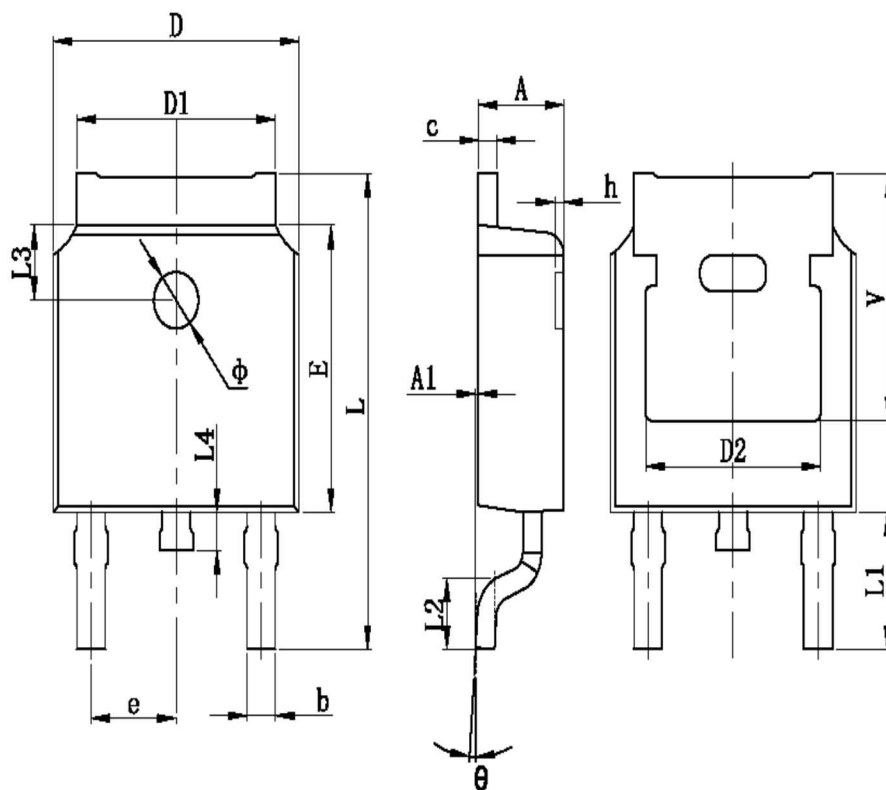
Figure1, TO251 package outline dimension



Symbol	Dimension In Millimeters			Dimension In Inches		
	Min	Nom	Max	Min	Nom	Max
A	2.200	2.300	2.400	0.087	0.091	0.094
A2	0.970	1.070	1.170	0.038	0.042	0.046
b	0.680	0.780	0.900	0.027	0.031	0.035
b2	0.000	0.040	0.100	0.000	0.002	0.004
b2'	0.000	0.040	0.100	0.000	0.002	0.004
b3	5.200	5.330	5.500	0.205	0.210	0.217
c	0.430	0.530	0.630	0.017	0.021	0.025
D	5.980	6.100	6.220	0.235	0.240	0.245
D1	5.300REF			0.209REF		
E	6.400	6.600	6.800	0.252	0.260	0.268
E1	4.630	-	-	0.182	-	-
e	2.286BSC			0.090BSC		
H	16.220	16.520	16.820	0.639	0.650	0.662
L1	9.150	9.400	9.650	0.360	0.370	0.380
L3	0.880	1.020	1.280	0.035	0.040	0.050
L5	1.650	1.800	1.950	0.065	0.071	0.077

■ Package Information

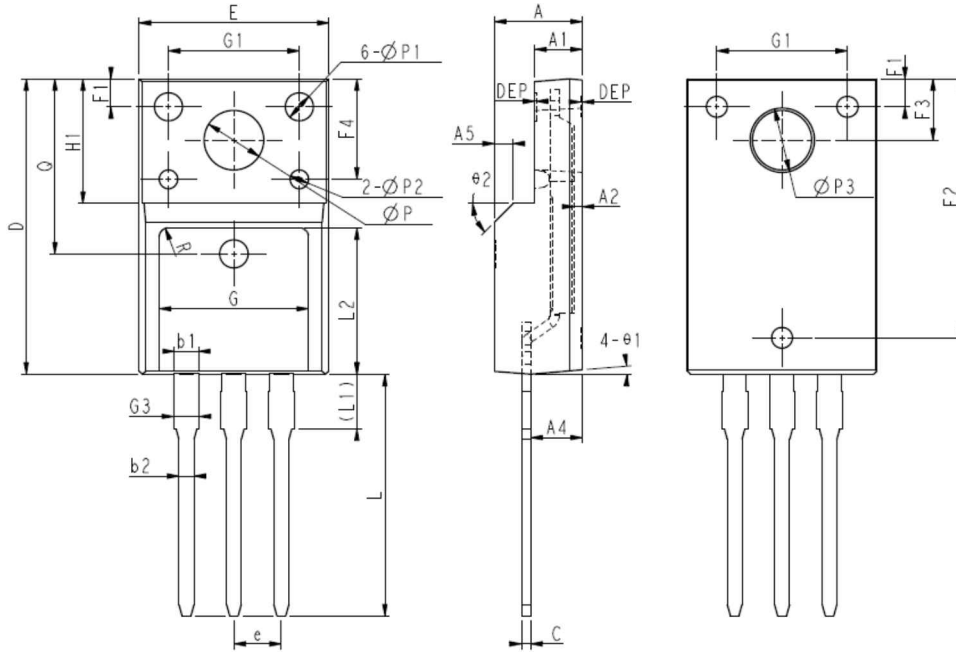
Figure2, TO252 package outline dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.660	0.860	0.026	0.034
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.350 REF.		0.211 REF.	

■ Package Information

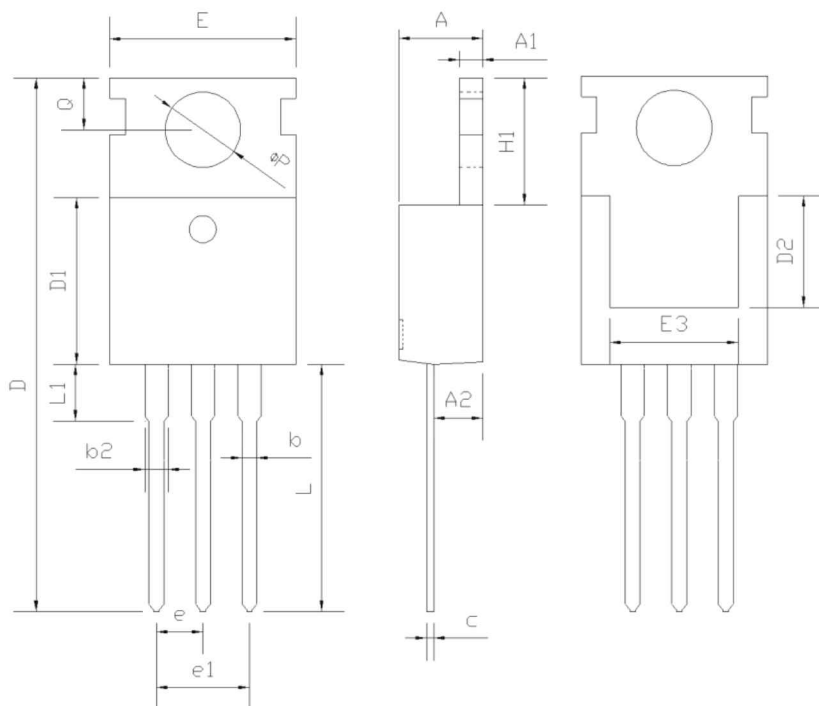
Figure3, TO220F package outline dimension



Symbol	Dimension In Millimeters			Dimension In Inches		
	Min	Nom	Max	Min	Nom	Max
E	10.000	10.160	10.320	0.394	0.400	0.406
E1	9.940	10.040	10.140	0.391	0.395	0.399
E2	9.360	9.460	9.560	0.369	0.372	0.376
A	4.500	4.700	4.900	0.177	0.185	0.193
A1	2.340	2.540	2.740	0.092	0.100	0.108
A2	0.430	-	0.480	0.017	-	0.019
A4	2.660	2.760	2.860	0.105	0.109	0.113
A5	1.00REF			0.039BSC		
c	0.450	0.525	0.600	0.018	0.021	0.024
D	15.670	15.870	16.070	0.617	0.625	0.633
Q	9.40REF			0.370REF		
H1	6.70REF			0.264REF		
e	2.54REF			0.100REF		
ΦP	3.18REF			0.125REF		
L	12.780	12.980	13.180	0.503	0.511	0.519
L1	2.830	2.930	3.030	0.111	0.115	0.119
L2	7.700	7.800	7.900	0.303	0.307	0.311
ΦP1	1.400	1.500	1.600	0.055	0.059	0.063
ΦP2	0.950	1.000	1.050	0.037	0.039	0.041
ΦP3	-	3.450	-	-	0.136	-
θ1	3°	5°	7°	3°	5°	7°
θ2	-	45°	-	-	45°	-
DEP	0.050	0.100	0.150	0.002	0.004	0.006
F1	1.000	1.500	2.000	0.039	0.059	0.079
F2	13.800	13.900	14.000	0.543	0.547	0.551
F3	3.200	3.300	3.400	0.126	0.130	0.134
F4	5.300	5.400	5.500	0.209	0.213	0.217
G	7.800	8.000	8.200	0.307	0.315	0.323
G1	6.900	7.000	7.100	0.272	0.276	0.280
G3	1.250	1.350	1.450	0.049	0.053	0.057
b1	1.230	1.280	1.380	0.048	0.050	0.054
b2	0.750	0.800	0.900	0.030	0.031	0.035
K1	0.650	0.700	0.750	0.026	0.028	0.030
R	-	0.5REF	-	-	0.020REF	-

■ Package Information

Figure4, TO220 package outline dimension



Symbol	Min	Nom	Max
A	4.37	4.57	4.77
A1	1.25	1.30	1.45
A2	2.20	2.40	2.60
b	0.70	0.80	0.95
b2	1.17	1.27	1.47
c	0.40	0.50	0.65
D	15.10	15.60	16.10
D1	8.80	9.10	9.40
D2	5.50	-	-
E	9.70	10.00	10.30
E3	7.00	-	-
e	2.54 BSC		
e1	5.08 BSC		
H1	6.25	6.50	6.85
L	12.75	13.50	13.80
L1	-	3.10	3.40
ΦP	3.40	3.60	3.80
Q	2.60	2.80	3.00

■ Ordering Information

Package	Units/Tube	Tubes/Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO251	75	66	4950	6	29700
TO252 Option1	75	66	4950	6	29700
TO220F	50	20	1000	6	6000
TO220	50	20	1000	6	6000

Package	Units/Tape	Tapes/Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO252 Option2	2500	2	5000	5	25000

■ Product Information

Product	Package	Pb Free	RoHS	Halogen Free
OSG07N65A	TO251	yes	yes	no
OSG07N65AF	TO251	yes	yes	yes
OSG07N65D	TO252	yes	yes	no
OSG07N65DF	TO252	yes	yes	yes
OSG07N65F	TO220F	yes	yes	no
OSG07N65FF	TO220F	yes	yes	yes
OSG07N65P	TO220	yes	yes	no
OSG07N65PF	TO220	yes	yes	yes